

# PATENT COOPERATION TREATY

## PCT

### INTERNATIONAL SEARCH REPORT

(PCT Article 18 and Rules 43 and 44)

Applicant's or agent's file reference <b>FGJB/CP/33558</b>	<b>FOR FURTHER ACTION</b> see Notification of Transmittal of International Search Report (Form PCT/ISA/220) as well as, where applicable, item 5 below.	
International application No. <b>PCT/GB 00/ 02630</b>	International filing date (day/month/year) <b>07/07/2000</b>	(Earliest) Priority Date (day/month/year) <b>08/07/1999</b>
Applicant  <b>AVX LIMITED</b>		

This International Search Report has been prepared by this International Searching Authority and is transmitted to the applicant according to Article 18. A copy is being transmitted to the International Bureau.

This International Search Report consists of a total of 2 sheets.

☒ It is also accompanied by a copy of each prior art document cited in this report.

**1. Basis of the report**

a. With regard to the **language**, the international search was carried out on the basis of the international application in the language in which it was filed, unless otherwise indicated under this item.

☐ the international search was carried out on the basis of a translation of the international application furnished to this Authority (Rule 23.1(b)).

b. With regard to any **nucleotide and/or amino acid sequence** disclosed in the international application, the international search was carried out on the basis of the sequence listing :

☐ contained in the international application in written form.

☐ filed together with the international application in computer readable form.

☐ furnished subsequently to this Authority in written form.

☐ furnished subsequently to this Authority in computer readable form.

☐ the statement that the subsequently furnished written sequence listing does not go beyond the disclosure in the international application as filed has been furnished.

☐ the statement that the information recorded in computer readable form is identical to the written sequence listing has been furnished

2. ☐ **Certain claims were found unsearchable** (See Box I).

3. ☐ **Unity of invention is lacking** (see Box II).

4. With regard to the **title**,

☒ the text is approved as submitted by the applicant.

☐ the text has been established by this Authority to read as follows:

5. With regard to the **abstract**,

☒ the text is approved as submitted by the applicant.

☐ the text has been established, according to Rule 38.2(b), by this Authority as it appears in Box III. The applicant may, within one month from the date of mailing of this international search report, submit comments to this Authority.

6. The figure of the **drawings** to be published with the abstract is Figure No.

☐ as suggested by the applicant.

☐ because the applicant failed to suggest a figure.

☒ because this figure better characterizes the invention.

**15a** \_\_\_\_\_

☐ None of the figures.

## INTERNATIONAL SEARCH REPORT

International Application No

P GB 00/02630

**A. CLASSIFICATION OF SUBJECT MATTER**  
 IPC 7 H01G9/012

According to International Patent Classification (IPC) or to both national classification and IPC

**B. FIELDS SEARCHED**

Minimum documentation searched (classification system followed by classification symbols)  
 IPC 7 H01G

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

WPI Data, PAJ, EP0-Internal

**C. DOCUMENTS CONSIDERED TO BE RELEVANT**

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 4 164 005 A (CHESELDINE DAVID M) 7 August 1979 (1979-08-07) column 5, line 5 - line 57 figure 3	1,2,10
A	US 5 357 399 A (SALISBURY IAN) 18 October 1994 (1994-10-18) cited in the application	
A	EP 0 758 788 A (ROHM CO LTD) 19 February 1997 (1997-02-19)	

☐ Further documents are listed in the continuation of box C.

☒ Patent family members are listed in annex.

## \* Special categories of cited documents :

- \*A\* document defining the general state of the art which is not considered to be of particular relevance
- \*E\* earlier document but published on or after the international filing date
- \*L\* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- \*O\* document referring to an oral disclosure, use, exhibition or other means
- \*P\* document published prior to the international filing date but later than the priority date claimed

\*T\* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

\*X\* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

\*Y\* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.

\*&\* document member of the same patent family

Date of the actual completion of the international search

3 October 2000

Date of mailing of the international search report

11/10/2000

Name and mailing address of the ISA

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Authorized officer

Goossens, A

# INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

P 00/02630

Patent document cited in search report		Publication date	Patent family member(s)	Publication date
US 4164005	A	07-08-1979	CA 1101947 A	26-05-1981
			GB 2003663 A, B	14-03-1979
US 5357399	A	18-10-1994	EP 0688030 A	20-12-1995
			CN 1085345 A, B	13-04-1994
			AT 187274 T	15-12-1999
			DE 69421906 D	05-01-2000
			DE 69421906 T	30-03-2000
			EP 0893808 A	27-01-1999
			ES 2139052 T	01-02-2000
EP 0758788	A	19-02-1997	US 5812366 A	22-09-1998
			CN 1145686 A	19-03-1997
			WO 9627889 A	12-09-1996

## PCT COOPERATION TREATY

PCT

## NOTIFICATION OF ELECTION

(PCT Rule 61.2)

From the INTERNATIONAL BUREAU

To:

Commissioner  
 US Department of Commerce  
 United States Patent and Trademark  
 Office, PCT  
 2011 South Clark Place Room  
 CP2/5C24  
 Arlington, VA 22202  
 ETATS-UNIS D'AMERIQUE  
 in its capacity as elected Office

Date of mailing (day/month/year) 27 March 2001 (27.03.01)	
International application No. PCT/GB00/02630	Applicant's or agent's file reference FGJB/CP/33558
International filing date (day/month/year) 07 July 2000 (07.07.00)	Priority date (day/month/year) 08 July 1999 (08.07.99)
Applicant HUNTINGTON, David	

1. The designated Office is hereby notified of its election made:

☒ in the demand filed with the International Preliminary Examining Authority on:

05 February 2001 (05.02.01)

☐ in a notice effecting later election filed with the International Bureau on:
2. The election ☒ was
☐ was not

made before the expiration of 19 months from the priority date or, where Rule 32 applies, within the time limit under Rule 32.2(b).

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland Facsimile No.: (41-22) 740.14.35	Authorized officer Zakaria EL KHODARY Telephone No.: (41-22) 338.83.38
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Claims

1. A method of manufacturing solid state capacitors comprising: providing an electrically conducting  
5 substrate; forming a plurality of upstanding porous electrically conducting anode bodies on a surface of the substrate, each body electrically connected to the substrate; forming an electrically insulating layer on the exposed surface area provided by the porous bodies;  
10 forming a conducting layer on the insulating layer; dividing the substrate into capacitor units, each comprising a portion of substrate provided with a porous capacitive body, and for each unit: providing a cathode terminal in electrical contact with the conducting layer  
15 on the capacitive body, providing an anode terminal in electrical contact with the substrate portion, characterised in that the cathode terminal is formed on a surface of the capacitive body distal to the substrate portion and the anode terminal is formed adjacent and  
20 substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, so that the capacitors have anode and cathode terminals on a common face.

2. A method as claimed in claim 1 wherein the electrically conducting wick is formed by a process in which a plurality of upstanding electrically conducting wick bodies are formed on the surface of the substrate  
5 alongside the anode bodies, the substrate division producing capacitor units comprising a portion of substrate provided with both a porous capacitive body and a wick body, and wherein the anode terminal is formed on a surface of the wick body distal to the substrate  
10 portion.
3. A method as claimed in claim 2 wherein the wick body is a porous conducting body.
- 15 4. A method as claimed in any preceding claim wherein the anode bodies are formed by configuration of a pre-form layer of porous conducting material applied to the surface of the substrate.
- 20 5. A method as claimed in claim 4 wherein the wick bodies are also formed by configuration of the pre-form layer.
- 25 6. A method as claimed in any claim 5 wherein the wick bodies are allowed to be provided with insulating and conducting layers along with the anode bodies, and

wherein an electrical connection through the insulating layer is provided by subsequent removal of the applied layers.

- 5     7. A method as claimed in claim 6 or claim 7 wherein the dividing of the substrate involves machining or cutting through a plane which passes through the wick bodies, thereby to expose un-coated wick material with which an anode terminal contact may be made.

10

8. A method as claimed in claim 6 wherein the removal of layers is carried out on a face of each wick distal to the substrate thereby to expose uncoated wick material with which an anode terminal contact may be made.

15

9. A method as claimed in claim 7 or claim 8 wherein a conductive material bridge electrically connects the anode terminal and the exposed un-coated wick material.

- 20     10. A state capacitor comprising a substrate portion and a capacitive body, which body comprises a porous anode body electrically connected to the substrate portion, an electrically insulating layer formed on the anode body surface area, and a conducting layer formed on the  
25     insulating layer, a surface of which capacitive body

distal to the substrate portion is provided with a cathode terminal, characterised in that an anode terminal is provided adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick  
5 providing electrical contact between the substrate portion and the anode terminal, thereby providing a capacitor having anode and cathode terminals on a common face.

10 11. A capacitor, or method of forming capacitors, as claimed in any preceding claim wherein in each capacitor there are a plurality of anode terminals adjacent and substantially co-planar with the cathode terminal, each anode terminal electrically connected to the substrate  
15 by an associated wick.

12. A capacitor, or method of forming a capacitor, as claimed in claim 11 wherein the wicks are each formed from the same porous conducting material as the anode  
20 body.



## PCT

## INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference FGJB/DC/33558	<b>FOR FURTHER ACTION</b> See Notification of Transmittal of International Preliminary Examination Report (Form PCT/IPEA/416)	
International application No. PCT/GB00/02630	International filing date (day/month/year) 07/07/2000	Priority date (day/month/year) 08/07/1999
International Patent Classification (IPC) or national classification and IPC H01G9/012		
Applicant AVX LIMITED et al.		

1. This international preliminary examination report has been prepared by this International Preliminary Examining Authority and is transmitted to the applicant according to Article 36.



2. This REPORT consists of a total of 6 sheets, including this cover sheet.

- ☒ This report is also accompanied by ANNEXES, i.e. sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications made before this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions under the PCT).

These annexes consist of a total of 3 sheets.

3. This report contains indications relating to the following items:

- I ☒ Basis of the report
- II ☐ Priority
- III ☐ Non-establishment of opinion with regard to novelty, inventive step and industrial applicability
- IV ☐ Lack of unity of invention
- V ☒ Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement
- VI ☐ Certain documents cited
- VII ☒ Certain defects in the international application
- VIII ☒ Certain observations on the international application

Date of submission of the demand 05/02/2001	Date of completion of this report 04.10.2001
Name and mailing address of the international preliminary examining authority:  European Patent Office D-80298 Munich Tel. +49 89 2399 - 0 Tx: 523656 epmu d Fax: +49 89 2399 - 4465	Authorized officer Lescop, E Telephone No. +49 89 2399 7974 

# INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/GB00/02630

## I. Basis of the report

1. With regard to the **elements** of the international application (*Replacement sheets which have been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to this report since they do not contain amendments (Rules 70.16 and 70.17)*):

### Description, pages:

1-28 as originally filed

### Claims, No.:

1-7 as received on 21/08/2001 with letter of 15/08/2001

### Drawings, sheets:

1/11-11/11 as originally filed

2. With regard to the **language**, all the elements marked above were available or furnished to this Authority in the language in which the international application was filed, unless otherwise indicated under this item.

These elements were available or furnished to this Authority in the following language: , which is:

- ☐ the language of a translation furnished for the purposes of the international search (under Rule 23.1(b)).  
☐ the language of publication of the international application (under Rule 48.3(b)).  
☐ the language of a translation furnished for the purposes of international preliminary examination (under Rule 55.2 and/or 55.3).

3. With regard to any **nucleotide and/or amino acid sequence** disclosed in the international application, the international preliminary examination was carried out on the basis of the sequence listing:

- ☐ contained in the international application in written form.  
☐ filed together with the international application in computer readable form.  
☐ furnished subsequently to this Authority in written form.  
☐ furnished subsequently to this Authority in computer readable form.  
☐ The statement that the subsequently furnished written sequence listing does not go beyond the disclosure in the international application as filed has been furnished.  
☐ The statement that the information recorded in computer readable form is identical to the written sequence listing has been furnished.

4. The amendments have resulted in the cancellation of:

- ☐ the description, pages:  
☐ the claims, Nos.:

# INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/GB00/02630

☐ the drawings, sheets:

5. ☐ This report has been established as if (some of) the amendments had not been made, since they have been considered to go beyond the disclosure as filed (Rule 70.2(c)):

*(Any replacement sheet containing such amendments must be referred to under item 1 and annexed to this report.)*

6. Additional observations, if necessary:

## V. Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

### 1. Statement

Novelty (N)	Yes:	Claims	1-7
	No:	Claims	

Inventive step (IS)	Yes:	Claims	1-7
	No:	Claims	

Industrial applicability (IA)	Yes:	Claims	1-7
	No:	Claims	

2. Citations and explanations  
**see separate sheet**

## VII. Certain defects in the international application

The following defects in the form or contents of the international application have been noted:  
**see separate sheet**

## VIII. Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:  
**see separate sheet**

**CONCERNING SECTION V:**

- 1). As the most pertinent prior art reference, US 4 164 005 A (hereinafter referred to as D1) has to be taken into account.
- 1.1 Regarding claim 1, D1 discloses (see especially figure 3 and column 5) a method of manufacturing solid state capacitors (column 4, line 67) comprising: providing an electrically conducting substrate (*tantalum anode sheet* 20, column 3, lines 30-31 and column 5, line 12), forming a plurality of upstanding porous anode bodies (*porous pad* 21 *of tantalum particles*, column 3, lines 30-32, column 5, line 15 and *plurality of capacitors*, column 5, lines 24-26) and forming wick bodies (*conductive bar* 40). Said bodies are implicitly electrically connected to the substrate (*bonded*, column 3, lines 32). The method of D1 further comprises the steps of forming an electrically insulating layer on the exposed surface area provided by the porous anode bodies (*tantalum oxide layer* 22, column 3, lines 37-40 and column 5, line 15, *insulative resin* 49, column 5, lines 29-36), a conducting layer onto it (*graphite and silver paint layers* 24, 25, column 3, lines 47 and figure 3), dividing the substrate into capacitors units (column 5, lines 24-34), providing a cathode terminal in electrical contact with the conducting layer (*cathode termination layers* 26, 27, 28, column 4, lines 59-60 and column 5, line 23) and an anode terminal in electrical contact with the substrate portion (*anode termination layers* 47, 48, column 4, lines 56-57 and column 5, lines 10-21). In D1, the cathode terminal is formed on a surface of the capacitive body distal to the substrate and the anode terminal is formed on a distal surface of the wick body and adjacent and co-planar to the cathode terminal (see figure 3 and column 5, lines 5-8). Furthermore, an electrically conducting wick is providing electrical contact between substrate portion (20) and anode terminal (47, 48). Consequently, the capacitors of D1 have anode and cathode terminals on a common face (see figure 3 and column 5, lines 5-8).

The subject-matter of claim 1 differs therefrom in that the anode and wick bodies are formed by configuring a pre-form layer of porous conducting material applied to a surface of the substrate.

Thus the method of claim 1 is new.

The problem to be solved by the invention consists in improving the method for

manufacturing solid state capacitors known from D1.

The solution claimed allows to simultaneously manufacture multiple capacitors having anode and cathode connections on the same face. Thus, the solution permits to reduce the footprint of the capacitors.

Since no documents cited in the international search report or in the application give an indication of the solution claimed, the subject-matter of claim 1 also involves an inventive step (Article 33(3) PCT).

- 1.2 The technical features of independent claim 6 corresponding to the ones of claim 1, the same arguments as recited above apply.
- 2). Claims 2-5 and 7 depending on claims 1 or 6, therefore meet the requirements of Articles 33(2) to (4) related to novelty, inventive step and industrial applicability.

**CONCERNING SECTION VII:**

- 1). Contrary to the requirements of Rule 5.1(a)(ii) PCT, the relevant background art disclosed in the document D1 is not mentioned in the description, nor is this document identified therein.
- 2). In claim 1, line 9, a pre-form layer is not specified.
- 3). According to the requirements of Rule 10.2 PCT, the terminology and the signs shall be consistent throughout the application. This requirement is not met in view of the use of the expressions "uncoated" and "un-coated" for the same feature (see claims 3-5).
- 4). The features of the device claims 6 and 7 are not provided with reference signs

**INTERNATIONAL PRELIMINARY  
EXAMINATION REPORT - SEPARATE SHEET**

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International application No. PCT/GB00/02630

placed in parentheses (Rule 6.2(b) PCT).

- 5). The references to the drawings in the description on page 27, line 11 and page 28, line 2 are misleading.  
The reference signs 105 and 106 on page 21 of the description are not supported by the drawings.
- 6). The description is not brought into conformity with the claims as required by rule 5.1(a)(iii) PCT.

**CONCERNING SECTION VIII:**

- 1). The present wording of claim 1 is unclear because there is doubt to which feature the capacitive body refers. There is not claimed that the capacitive body is an anode body coated with a dielectric and a conductive layer.
- 2). Claim 7 should be either a device or a method claim, since it is presently not clear to which category it belongs.
- 3). The vague term **substantially** in claims 1, 6 and 7 should be avoided.

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## Claims

1. A method of manufacturing solid state capacitors comprising: providing an electrically conducting substrate; providing a pre-form layer of porous conducting material applied to a surface of the substrate, forming a plurality of upstanding porous anode bodies and wick bodies by configuring of the pre-form, each body electrically connected to the substrate; forming an electrically insulating layer on the exposed surface area provided by the porous anode bodies; forming a conducting layer on the insulating layer on the anode bodies; dividing the substrate into capacitor units, each comprising a portion of substrate provided with a porous capacitive body and a wick body, and for each unit: providing a cathode terminal in electrical contact with the conducting layer on the capacitive body, providing an anode terminal in electrical contact with the substrate portion,
- wherein the cathode terminal is formed on a surface of the capacitive body distal to the substrate portion and the anode terminal is formed on a distal surface of the wick body which anode terminal is adjacent and substantially co-planar with the cathode terminal, with the electrically conducting wick body providing

AMENDED SHEET

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electrical contact between the substrate portion and the anode terminal, so that the capacitors have anode and cathode terminals on a common face.

5 2. A method as claimed in claim 1 wherein the wick bodies are allowed to be provided with insulating and conducting layers along with the anode bodies, and wherein an electrical connection through the insulating layer is provided by subsequent removal of the applied  
10 layers.

3. A method as claimed in claim 2 wherein the dividing of the substrate involves machining or cutting through a plane which passes through the wick bodies, thereby to  
15 expose un-coated wick material with which an anode terminal contact may be made.

4. A method as claimed in claim 2 wherein the removal of layers is carried out on a face of each wick distal to  
20 the substrate thereby to expose uncoated wick material with which an anode terminal contact may be made.

5. A method as claimed in claim 3 or claim 4 wherein a conductive material bridge electrically connects the  
25 anode terminal and the exposed un-coated wick material.

AMENDED SHEET



6. A solid state capacitor comprising a substrate portion and a capacitive body, which body comprises a porous anode body electrically connected to the substrate portion, an electrically insulating layer formed on the anode body surface area, and a conducting layer formed on the insulating layer, a surface of which capacitive body distal to the substrate portion is provided with a cathode terminal, characterised in that an anode terminal is provided adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, thereby providing a capacitor having anode and cathode terminals on a common face, and wherein the wick is formed from the same porous conducting material as the anode body.

7. A capacitor, or method of forming capacitors, as claimed in any preceding claim wherein in each capacitor there are a plurality of anode terminals adjacent and substantially co-planar with the cathode terminal, each anode terminal electrically connected to the substrate by an associated wick.

AMENDED SHEET

(19) World Intellectual Property Organization  
International Bureau



(43) International Publication Date  
1 February 2001 (01.02.2001)

PCT

(10) International Publication Number  
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(51) International Patent Classification<sup>7</sup>: **H01G 9/012**

(21) International Application Number: **PCT/GB00/02630**

(22) International Filing Date: **7 July 2000 (07.07.2000)**

(25) Filing Language: **English**

(26) Publication Language: **English**

(30) Priority Data:  
9916047.5 8 July 1999 (08.07.1999) GB  
9926894.8 12 November 1999 (12.11.1999) GB

(71) Applicant (for all designated States except US): **AVX LIMITED [GB/GB];** Tantalum Division, Paignton, Devon TQ4 7ER (GB).

(72) Inventor; and

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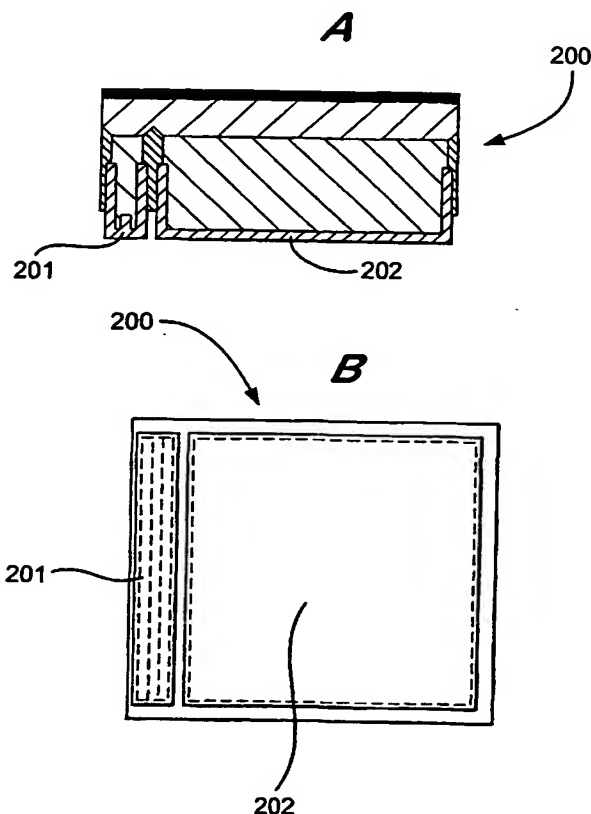
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(81) Designated States (national): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CR, CU, CZ, DE, DK, DM, DZ, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, TZ, UA, UG, US, UZ, VN, YU, ZA, ZW.

(84) Designated States (regional): ARIPO patent (GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZW), Eurasian

[Continued on next page]

(54) Title: **SOLID STATE CAPACITORS AND METHODS OF MANUFACTURING THEM**



(57) Abstract: The present invention relates to the field of solid state capacitors. The invention particularly relates to capacitors of the type in which a powder-formed valve action material, typically tantalum, forms a highly porous anode body portion of a solid state capacitor. According to one aspect of the present invention there is provided a method of manufacturing a solid state capacitor comprising: providing an electrically conducting substrate; forming a plurality of upstanding porous electrically conducting anode bodies on a surface of the substrate, each body electrically connected to the substrate; forming an electrically insulating layer on the exposed surface area provided by the porous bodies; forming a conducting layer on the insulating layer; dividing the substrate into capacitor units, each comprising a portion of substrate provided with a porous capacitive body, and for each unit: providing a cathode terminal in electrical contact with the conducting layer on the capacitive body, providing an anode terminal in electrical contact with the substrate portion, characterised in that the cathode terminal is formed on a surface of the capacitive body distal to the substrate portion and the anode terminal is formed adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, so that the capacitors have anode and cathode terminals on a common face. By forming a capacitor with anode and cathode connections on a common face the footprint of the capacitor is minimized, whilst facilitating connection with a circuit board.

WO 01/08178 A1



patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

*For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.*

**Published:**

— *With international search report.*

**Solid State Capacitors and  
Methods of Manufacturing Them**

The present invention relates to the field of solid state  
5 capacitors. The invention particularly relates to  
capacitors of the type in which a powder-formed valve  
action metal forms a highly porous anode body portion of  
a capacitor, an electrically insulating dielectric layer  
is formed though the porous structure of the anode body,  
10 and a conducting cathode layer is formed on the  
dielectric layer and which is then electrically connected  
to a cathode terminal, the anode body being electrically  
connected to an anode terminal.

15 US patent specification no. 5,357,399 (Salisbury)  
describes a method for simultaneously manufacturing  
multiple such capacitors from a porous tantalum layer  
sintered to a tantalum substrate. The layer is machined  
to form anode body portions of each capacitor. After  
20 processing a top plate (substrate lid) is bonded to the  
processed anode body top ends. The plate forms a lid  
which, after machining of the substrate/anode body/plate  
sandwich, becomes the cathode terminal of each capacitor.  
PCT application GB99/03566 concerns a modified version  
25 of the Salisbury method in which the volumetric

efficiency of the capacitors produced is optimized by removing the need for a substrate lid as the cathode terminal of each capacitor, thereby increasing the specific capacitive volume.

5

The foregoing methods permit the manufacture of very small but highly volume efficient capacitors. However the continued pressure of electronic circuit board design towards miniaturisation of components and ease of assembly of such boards maintains a continued need for capacitors of improved volumetric efficiency and reduced component windows (or footprint) on the circuit board.

The present invention seeks to provide improved capacitors and improved methods of manufacturing such capacitors.

According to one aspect of the present invention there is provided a method of manufacturing a solid state capacitor comprising:

providing an electrically conducting substrate; forming a plurality of upstanding porous electrically conducting anode bodies on a surface of the substrate, each body electrically connected to the substrate; forming an electrically insulating layer on the exposed surface area

provided by the porous bodies; forming a conducting layer on the insulating layer; dividing the substrate into capacitor units, each comprising a portion of substrate provided with a porous capacitive body, and for each  
5 unit: providing a cathode terminal in electrical contact with the conducting layer on the capacitive body, providing an anode terminal in electrical contact with the substrate portion,  
characterised in that the cathode terminal is formed on  
10 a surface of the capacitive body distal to the substrate portion and the anode terminal is formed adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, so  
15 that the capacitors have anode and cathode terminals on a common face.

By forming a capacitor with anode and cathode connections on a common face the footprint of the capacitor is  
20 minimized, whilst facilitating connection with a circuit board.

The electrically conducting wick may be formed by a process in which a plurality of upstanding electrically  
25 conducting wick bodies are formed on the surface of the

substrate alongside the anode bodies, the substrate division producing capacitor units comprising a portion of substrate provided with both a porous capacitive body and a wick body, and wherein the anode terminal is formed  
5 on a surface of the wick body distal to the substrate portion.

In a preferred embodiment, the anode bodies are formed by configuration of a pre-form layer of porous conducting  
10 material applied to the surface of the substrate. Conveniently, the wick body is a porous conducting body, which may be formed by configuration of the pre-form layer.

15 By "configuration" the reader is intended to understand any shaping or forming process which can form the required bodies. Typical examples are cutting and machining, for example by saws or cutting wheels. However it may be that the worker may wish to employ laser  
20 cutting, water cutting, etching or other known methods to form the body shapes.

The wick bodies may be allowed to be provided with insulating and conducting layers along with the anode  
25 bodies. In this case an electrical connection through the

5

insulating layer is provided by subsequent removal of the applied layers. This removal may be by machining, cutting grinding, etching or the like, so long as the underlying conducting wick material is exposed.

5

In one embodiment of the invention, the dividing of the substrate preferably involves machining or cutting through a plane which passes through the wick bodies, thereby to expose un-coated wick material with which an anode terminal contact may be made. In this way no separate cutting process or machining is necessary to remove the insulating layers; it is included in the substrate division process.

10 In another embodiment the removal of insulating and conducting layers is carried out on a face of each wick distal to the substrate thereby to expose uncoated wick material with which an anode terminal contact may be made. This has the advantage of exposing a surface which is adjacent and co-planar the anode body top face, simplifying contact with the terminals.

15 A conductive material bridge may electrically connect the anode terminal and the exposed un-coated wick material.

20 Typically the bridge material is applied as a conducting



paste (e.g. silver paste) which sets to form a solid coating. To enhance the contact a carbon layer may first be applied.

5 In another aspect of the invention there is provided a state capacitor comprising a substrate portion and a capacitive body, which body comprises a porous anode body electrically connected to the substrate portion, an electrically insulating layer formed on the anode body  
10 surface area, and a conducting layer formed on the insulating layer, a surface of which capacitive body distal to the substrate portion is provided with a cathode terminal, characterised in that an anode terminal is provided adjacent and substantially co-planar with  
15 the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, thereby providing a capacitor having anode and cathode terminals on a common face.

20

In certain embodiments, in each capacitor, there are a plurality of anode terminals adjacent and substantially co-planar with the cathode terminal, each anode terminal electrically connected to the substrate by an associated  
25 wick. The wicks may each be formed from the same porous

conducting material as the anode body.

According to another aspect of the invention there is provided a method of manufacturing multiple solid state  
5 capacitors comprising a method as hereinbefore described wherein a plurality of anode and wick bodies are formed on the substrate, and the substrate is divided to provide a plurality of individual capacitor units.

10

As the terminals are coplanar, the capacitor may stand on a flat surface with the cathode terminal and anode terminal contacting the flat surface. This makes the capacitor very well adapted for placement on and  
15 attachment to a circuit board.

The pre-form may be applied to the substrate by laying a green, unsintered mixture of valve action metal powder and binder/lubricant on the substrate. The green mixture  
20 may then be sintered to fuse the powder into a solid highly porous pre-form, the binder/lubricant being burnt off during sintering.

The pre-form layer may be machined to form the anode  
25 bodies and the wick bodies. Typically longitudinal and

lateral grinding cuts may be employed in order to produce an array of rectilinear anode and wick bodies on the substrate, separated by "streets" corresponding to the path of the grinding cut. Naturally more complex shapes  
5 can be produced by conventional machining techniques, as required.

The processing is facilitated if both wick and anode bodies are coated with the insulating layer and the  
10 conducting cathode layer. An alternative would be to mask the wick bodies in order to prevent coating of the anode bodies from, but this would be a rather difficult and complicated process.

15 The insulating layer may be a dielectric layer of an oxide of the valve action material, applied for example by conventional anodization techniques in order to build up gradually an oxide of the required thickness and integrity. In one example, in which the valve action  
20 layer is tantalum, a layer of tantalum pentoxide is built up on the bodies.

The conducting layer may be applied by dipping of the anode and wick bodies into a precursor solution of, for  
25 example manganese nitrate solution. The layer of

manganese nitrate formed on the bodies may be heated to oxidise the nitrate to manganese dioxide. Repeated dipping steps may be necessary in order to build-up the optimum cathode layer.

5

building-up of the conducting or "cathode" layer completes the formation of the anode body into a capacitive body.

10 In the case where both the anode bodies and wick bodies are subject to the application of an insulating layer and a cathode layer it is necessary to isolate electrically the cathode layer material on the anode bodies from that on the wick bodies, in order to prevent a short circuit  
15 in the final capacitors. This may involve removal of all cathode layer material bridging the anode and wick bodies. Typically this may be achieved by a grinding cut through the conducting layer, and inevitably through the insulating layer also. In this case a replacement  
20 electrically insulating layer may be formed on any exposed surfaces revealed by cathode layer removal. This process is known as reformation. Again this may be conducted by a re-anodization process.

25 As well as isolating the conducting layers of the

respective anode bodies and wick bodies one from another, it is necessary to remove conducting layer and insulating layer material from those parts of the wick bodies which are to contact or form the anode terminals, so that an electrical connection to the valve-action substrate material may be made. Removal of the layers may be by machining, for example grinding. In one example grinding cuts are made along a top surface of each wick body, thereby exposing valve action material. The top surface may then be subjected to a termination process to form the anode terminal. Typically this involves application of a first layer of conducting carbon paste which is then cured. Next a second layer of conducting silver paste is applied, and cured. Finally a solder-facilitating tri-alloy layer, or the like, may be applied to enable a good soldered contact to be made. A similar termination process is also carried out on a top surface of the capacitive body, in which carbon and silver layers are formed on the conducting cathode layer of the top surface, optional followed by application of a tri-alloy layer. These conducting layers provide a terminal for electrical connection, by for example soldering, to an electrical or electronic circuit.

In the un-divided substrate, the spaces between the anode

## 11

bodies and the cathode bodies may be filled with an insulating material, for example a liquid plastics resin which solidifies to form a protective encapsulation of the bodies. Naturally the resin should leave the upper  
5 surface of the capacitive and wick bodies exposed, by masking if necessary. Other wise removal of the resin layer back to expose these faces is required.

The next step which must be carried out is separation of  
10 the or each capacitor unit from the bulk substrate. This may be achieved by machining by for example a grinding cut. If necessary a rigid backing support may be provided for the substrate to as to provide the necessary structural rigidity to permit cutting without damaging  
15 the capacitors.

In another aspect of the invention the dividing comprises cutting along a plane or path which intersects with one or more wick bodies, thereby to cut through or remove  
20 conducting layer material and insulating layer material applied to the wick, and to expose a cut surface of uncoated wick body. Preferably the wick bodies may be arranged on the substrate in rows, and the dividing comprises cutting along one or more of the rows.

The cutting plane preferably intersects with a wick body surface region distal from the associated anode body of the capacitor unit to be divided.

- 5 The cutting is preferably carried out through a plane or planes perpendicular or substantially perpendicular to the plane of the substrate. The cutting may comprise grinding, but could also include water cutting or other cutting methods.

10

- The terminal may be provided on the expose cut surface of the wick body by a termination process comprising liquid coating of that surface by a conducting paste, and allowing the coating to solidify. The termination processes may further comprise electro-plating the solidified coating to form a layer of metallic material on the respective body or bodies.
- 15

- Preferably, before dividing, the substrate is coated with a protective insulating material which infiltrates in between the anode and wick bodies, and wherein the dividing process comprises cutting along the protective material, thereby to leave a sidewall of protective material around each anode and cathode body of each cathode portion, the wall being absent in the said side
- 20
- 25

regions of the anode bodies which intersect with the cut.

The protective material may be a resin material which is infiltrated as a liquid and subsequently allowed to set.

5

A termination layer of metal plate may be applied, for example by electrodeposition. Typically a layer of nickel and tin/lead or gold is applied. this provides a solder compatible surface for electrical connection.

10

Following is a description by way of example only and with reference to the accompanying drawings of methods of putting the present invention into effect.

15 In the drawings:-

Figure 1 is a plan view of a portion of a substrate to be processed according to one embodiment of the present invention.

20

Figure 2 is a perspective view of a small area of the substrate portion shown in figure 1.

Figures 3A, 3B and 4A, 4B show an unfinished and finished  
25 capacitor made according to the present invention.



14

Figures 5A, 5B, 5C and 5D show, respectively, underside, top face, side view and sectional views of a finished capacitor according to one embodiment of the present invention.

5

Figures 6A, 6B, 6C and 6D show, respectively, underside, top face, side view and sectional views of a finished capacitor according to another embodiment of the present invention.

10

Figures 7 to 14 illustrate schematically a process according to the present invention. Figures 15 to 17 show individual capacitors produced by the method.

15 In particular:-

Figure 7A is a plan view of a tantalum substrate having anode bodies and a cathode body formed thereon. Figure 7B is a side view of the same substrate.

20

Figures 8A & 8B show isolation of the cathode body from the anode body.

Figures 9A & 9B show the formation of anode terminal connections through the anode bodies.

25

15

Figures 10A & 10B show the termination process.

Figures 11A & 11B show an encapsulation process.

5 Figures 12A & 12B show a final step in the termination process.

Figure 13 shows a cutting process for separating individual capacitors.

10

Figures 14A & 14B show one example of a capacitor produced by the method of the present invention.

Figure 15A & 15B show a second example of a capacitor  
15 according to the present invention.

Figures 16A & 16B show a third example of a capacitor produced according to a method according to the present invention.

20

**First embodiment of a method according to the invention.**

A solid substrate of, for example, 0.25 mm thick tantalum wafer 10 is shown in figure 1. A top surface 9 of the substrate is covered with a dispersion of tantalum grains  
25 (not shown). The grains are fused to the tantalum wafer

by sintering, thereby to form a seed layer (not shown).  
A conventional mixture of tantalum powder and  
binder/lubricant is then pressed onto the seed layer. The  
seed layer provides mechanical keying and enhances the  
5 bond between the green (un-sintered) powder and the  
substrate. The green powder mixture is then sintered to  
form an inter-connected, highly porous matrix of fused  
tantalum powder particles. The binder is burned off  
during the sintering process. This leaves a uniform layer  
10 of porous tantalum on the solid wafer.

The porous layer mixture is machined to form an  
orthogonal pattern of channels in rows 11 and columns 12.  
The rows are machined in closely spaced parallel pairs  
15 13,14 so that an array of generally square 15 and oblong  
16 bodies are formed on the substrate, as shown in the  
figure. The square bodies 15 will form the capacitive  
bodies in the final capacitors, so are termed capacitive  
bodies hereafter. The oblong bodies 16 will form the  
20 anode terminal wicks.

The substrate and its array of upstanding bodies 15,16  
is then subjected to a conventional anodization treatment  
which forms a thin dielectric layer of tantalum pentoxide  
25 on the tantalum of the substrate and through the porous

network of the powder-formed bodies. Anodization may be repeated several times in order to build-up the required depth and integrity of dielectric layer. The dielectric layer forms an electrically insulating layer for providing capacitance in the final devices.

Next the substrate 10 and bodies 15,16 are is coated with a cathode layer-forming solution of manganese nitrate. The solution enters into the porous network to form a manganese nitrate layer on the dielectric layer. The manganese nitrate is heated in an oxygen-containing atmosphere that oxidises the manganese nitrate, forming manganese dioxide. The coating and heating process may be repeated in order to build up the required conductive. The manganese dioxide layer is electrically conducting and provides a layer providing electrical contact with a cathode terminal in the final capacitors.

The coated capacitive bodies 15 and wick bodies 16 must now be isolated from one another so that capacitor unit pairs of bodies do not short circuit in the final capacitors. The wick bodies are isolated from the capacitive bodies by means of fine grinding cuts. The cuts run along the rows 13 to form grooves indicated by the lines 20 in figure 1. These cuts impinge into the

underlying substrate, thereby passing through both the manganese oxide cathode layer and the tantalum pentoxide dielectric layer. Once the wick and capacitive bodies have been isolated, the anodization process is repeated  
5 in order to form a protective tantalum pentoxide layer on the exposed tantalum of the isolation groove cuts.

Respective layers of carbon and silver paste (not shown) are applied to the top ends of the bodies, and extending  
10 about 2/3 of the way down the sidewalls of each. This layer provides a good electrical contact for the formation of terminals on the final capacitors.

An epoxy resin liquid is infiltrated into the rows and  
15 columns to occupy the space in between bodies on the substrate. A lid (not shown) is placed on the body top ends in order to constrain the resin to below the top ends of the bodies. The resin is allowed to set, and the lid layer removed.

20

The substrate is now divided to provide a plurality of individual capacitor units. The division is conducted by means of a fine grinding wheel. Each column cut follows along the centre line of each column 12, through a plane  
25 perpendicular to the plane occupied by the substrate.

Each row cut follows a direction parallel to the oblong bodies, offset to the side of the row 14 so that the cut impinges on each sidewall of the wick bodies 16 along that row. The path of the respective row cuts is shown by the dotted line C in figure 1. Because the cut impinges on the wick sidewall, the manganese oxide and dielectric layer are ground away to expose the metal porous matrix of the body.

The cutting process is shown in more detail in figure 2, which shows two capacitor units 30 and 31. The column cuts have already been made. The two dicing wheels 32,33 are shown moving through the cutting path C, about to impinge on the outside wall of each anode body 16. Once cutting is complete, a plurality of unfinished capacitor units is left, one of which 34 is shown in figure 3. Figure 3A is a top view of the unfinished capacitor, simply showing the diced substrate portion 35 of the capacitor. Figure 3B is a sectional side view along the line AA'. The exposed wick sidewall face 36 is on the left hand side of the figure. The capacitive body is surrounded by a sleeve of resin material 37. Each body is shown with the silver and carbon paste layers 38. The exposed face 36 is dipped into a liquid silver paste to coat the face and local region of the capacitor with an

end cap 39, as shown in figure 4A and 4B. By coating onto exposed tantalum metal an extremely good electrical contact is made, preferably overlapping with the substrate to provide direct contact therewith. In addition a direct electrical contact is made with the substrate layer, so enhancing the electrical contact with the metal matrix of the cathode body in the bulk of the capacitor.

10 In order to finish the capacitor a metal plate layer may be applied to the exposed surfaces 39,38 of the respective anode terminal (wick) and cathode terminal (capacitive body). This can be applied by known methods such as electro-deposition and sputter coating. In a preferred arrangement a layer of nickel is applied followed by a tin-lead layer. The metal plate layer provides a solder compatible surface permitting soldering of the component to a printed circuit board. Figure 5 shows the final capacitor.

20

Figure 6 shows an alternative capacitor 100 according to the present invention. Each capacitor portion of the substrate is formed with two wick bodies 101,102. In between these two is a capacitive body 103. It will be appreciated that the alteration to the process will

involve forming thicker wick bodies. The dicing cut is directed along the centre line of each wick body so that each body is divided in two. One half becomes a first wick body of one capacitor unit, and the other becoming  
5 the first wick body of another capacitor unit. Second wick bodies are formed similarly at the opposite ends of each capacitor unit.

The result is a capacitor having the structure shown in  
10 figure 6, with two anode terminals 105 and a central face cathode terminal 106.

**Second embodiment of a method according to the present invention.**

15 A solid substrate of, for example, 0.25 mm thick tantalum wafer is provided. One surface of the substrate is covered with a dispersion of tantalum grains. The grains are fused to the tantalum plate by sintering to form a seed layer. A conventional mixture of tantalum powder and  
20 binder/lubricant is then pressed onto the seed layer. The seed layer provides mechanical keying and enhances the bond between the green (unsintered) powder and the substrate. The green powder mixture is then sintered to form an inter-connecting highly porous matrix of fused  
25 tantalum powder particles. The binder is burned off



during the sintering process. Leaving a pre-form layer of sintered tantalum fused to the tantalum substrate.

5 Figures 7A and 7B show further machining processing. For the sake of clarity the processing of a single capacitor is shown. In practice a plurality of capacitors will be processed simultaneously on a single tantalum substrate. The porous layer 112 has been fused to a surface 111 of  
10 the substrate 110. The porous layer is now machined to form a plurality of vertical 114 and horizontal 115 slots in the porous layer. The slots define a network of square-plan capacitive bodies (one only shown as 116) upstanding on the substrate base. The slots also form  
15 four elongate rectangular plan wick bodies 117 along each side of the lands. At each corner of the capacitive bodies a square-plan wick feature 118 is formed.

The substrate and its network of upstanding bodies and  
20 is then subjected to a conventional anodization treatment which forms a thin dielectric layer of tantalum pentoxide on the tantalum of the substrate and through the porous network of the powder-formed layer. Anodization may be repeated several times in order to build-up the required  
25 depth and integrity of dielectric layer. The dielectric

layer forms an electrically insulating layer for providing capacitance in the final devices.

Next the porous layer is coated, by repeated dipping,  
5 with a cathode layer forming solution of manganese nitrate. The solution enters into the porous network to form a manganese nitrate layer on the dielectric layer. The manganese nitrate is heated in an oxygen-containing atmosphere that oxidises the manganese nitrate, forming  
10 manganese dioxide. The coating and heating process may be repeated in order to build up the required layer. The manganese dioxide layer is electrically conducting and provides a cathode layer for electrical connection to a cathode terminal.

15 The coated capacitive bodies 116 and wick bodies 117,118 must now be isolated from one another. The wick bodies are isolated from the cathode features by means fine grinding cuts. The cuts run along the horizontal and  
20 vertical slots 114 & 115 to form vertical isolation cuts 208 and horizontal isolation cuts 209. These cuts impinge into the underlying substrate as shown in figure 8B, thereby passing through both the manganese oxide cathode layer and the tantalum pentoxide dielectric layer. Once  
25 the respective wick and capacitive bodies have been

isolated, the anodization process is repeated in order to form a protective tantalum pentoxide layer on the exposed tantalum of the isolation cuts.

5 Next horizontal and vertical cuts are made into and along the distal top ends of the wick bodies 117 & 118, as shown in figures 9A & 9B. These cuts to form elongate slots 122 in the top end of the rectangular wick features 117 and crossed slots 123 on the top end of the square  
10 wick features 118. These slots cut through both the manganese oxide cathode layer and the dielectric layer formed on the anode bodies, thereby permitting electrical connection to the porous metal interior of the wick bodies.

15

The next stage of the process concerns the formation of terminals of each capacitor (i.e. the termination process). First a conducting carbon paste layer (not shown) is deposited on end regions 141 and upper side  
20 regions 142 of each capacitive and wick body. The carbon layer is allowed to harden by curing. Second a conducting silver paste layer 143 is deposited on the carbon layer, and itself allowed to cure.

25 An optional conductive plating may be applied onto the

top free surface 207 of the substrate 110 in order to provide an alternative anode terminal on the substrate free surface. The conductive layer may be a sputtered tri-metal system, to aid soldered connection to a  
5 circuit.

Figures 11A and 11B show an encapsulation process. The slots 114,115 between capacitive 116 and wick bodies are filled with an electrically insulating resin 155.  
10 Initially a removable masking layer (not shown) is applied to the silvered end regions of the anode and cathode bodies in order to shield them from unwanted contamination by resin. Liquid resin 155 is injected into the slots in order to encapsulate the sides of the anode  
15 and cathode features. The resin is permitted to solidify. The masking layer is removed to expose the silvered upper ends of each anode and cathode feature. Other encapsulation techniques may be used, including fluidised bed powder filling, flip chip underfill resin  
20 technology and simple liquid resin dispensing into the slots. Each of these techniques is within the common general knowledge of the skilled person.

The silvered exposed surfaces are provided with further  
25 processing to facilitate electrical connection with an

electrical circuit or attachment to a circuit board, as shown in figures 12A and 12B. Specifically, an array of silver bumps 156 is applied to the exposed surface of the anode bodies and the cathode bodies. These raised bump features provide contact points which may readily fuse with solder to form an electrical connection to an electronic or electrical circuit in which the capacitor is integrated.

Figure 13 shows a sectional side view through a capacitor, illustrating the separation of the individual capacitor by division of the bulk substrate. The substrate 110 is attached to a glass plate 160 by means of a suitable adhesive or alternatively mounted by means of a UV releasable adhesive tape 161. Cutting wheels 162 and 163 are used to cut through the resin channels separating individual capacitors. The cut continues through the substrate, through any adhesive tape and, if necessary, into the glass base 160 so as to ensure a clean cut. Horizontal and vertical cuts are combined to produce a grid of cuts which separate each individual capacitor (only one capacitor from the array is shown). The capacitors may be released from the glass plate by degradation of the adhesive in the case of an adhesive mounting, or by exposure of the plate to ultra violet

light. The UV light degrades the adhesive layer on the tape so that the capacitors may be detached from the backing tape.

5 Figures 14A and 14B, 15A and 15B, 16A and 16B each show examples of alternative configurations for capacitors produced by methods generally in accordance with the foregoing.

10 **Example 1**

In figure 14A a capacitor 180 is shown having eight anode terminals, four of them square plan 181 and four of them rectangular elongate plan 182. There is a central cathode terminal pad 183. The terminals are provided with a  
15 dispersion of silver paste electrical connection bumps.

**Example 2**

In figures 15A & 15B a capacitor 190 is shown having two elongate rectangular plan anode terminals 191. There is  
20 a central cathode terminal pad 192. The terminals left clean of silver paste electrical connection bumps. This configuration is produced by reducing the number of grinding cuts applied to the porous pre-form on the substrate during initial machining, as compared with  
25 example 1 above and in the foregoing method.

**Example 3**

In figure 16A & 16B a capacitor 200 is shown having one elongate anode terminal 201 and one central square plan cathode terminal pad 202. Again, this configuration is readily obtained by reducing the number of grinding cuts carried out on the porous pre-form applied to the substrate during initial machining, as compared to examples 1 and 2 above. This particular capacitor is shown without the optional silver contact bumps.

10

Typical production specifications for capacitors produced by the methods of this invention are varied but, for example, the method can be used to produce low-profile capacitors having dimensions of 10x10x1 mm, using a substrate of 0.25 mm tantalum, a seed layer of 0.25g KTA tantalum powder, a pre-form press height of 0.95 mm, using S700 tantalum powder and a press density of 5.5 g/cc and a forming ratio of 4:1. The typical electrical specifications are 470 micro farads for 10 volts rated capacitors,  $L_i$  being about 5 micro-amps.

20

## Claims

1. A method of manufacturing solid state capacitors comprising: providing an electrically conducting substrate; forming a plurality of upstanding porous electrically conducting anode bodies on a surface of the substrate, each body electrically connected to the substrate; forming an electrically insulating layer on the exposed surface area provided by the porous bodies; forming a conducting layer on the insulating layer; dividing the substrate into capacitor units, each comprising a portion of substrate provided with a porous capacitive body, and for each unit: providing a cathode terminal in electrical contact with the conducting layer on the capacitive body, providing an anode terminal in electrical contact with the substrate portion, characterised in that the cathode terminal is formed on a surface of the capacitive body distal to the substrate portion and the anode terminal is formed adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, so that the capacitors have anode and cathode terminals on a common face.



2. A method as claimed in claim 1 wherein the electrically conducting wick is formed by a process in which a plurality of upstanding electrically conducting wick bodies are formed on the surface of the substrate alongside the anode bodies, the substrate division producing capacitor units comprising a portion of substrate provided with both a porous capacitive body and a wick body, and wherein the anode terminal is formed on a surface of the wick body distal to the substrate portion.

3. A method as claimed in claim 2 wherein the wick body is a porous conducting body.

4. A method as claimed in any preceding claim wherein the anode bodies are formed by configuration of a pre-form layer of porous conducting material applied to the surface of the substrate.

5. A method as claimed in claim 4 wherein the wick bodies are also formed by configuration of the pre-form layer.

6. A method as claimed in any claim 5 wherein the wick bodies are allowed to be provided with insulating and conducting layers along with the anode bodies, and

wherein an electrical connection through the insulating layer is provided by subsequent removal of the applied layers.

- 5 7. A method as claimed in claim 6 or claim 7 wherein the dividing of the substrate involves machining or cutting through a plane which passes through the wick bodies, thereby to expose un-coated wick material with which an anode terminal contact may be made.

10

8. A method as claimed in claim 6 wherein the removal of layers is carried out on a face of each wick distal to the substrate thereby to expose uncoated wick material with which an anode terminal contact may be made.

15

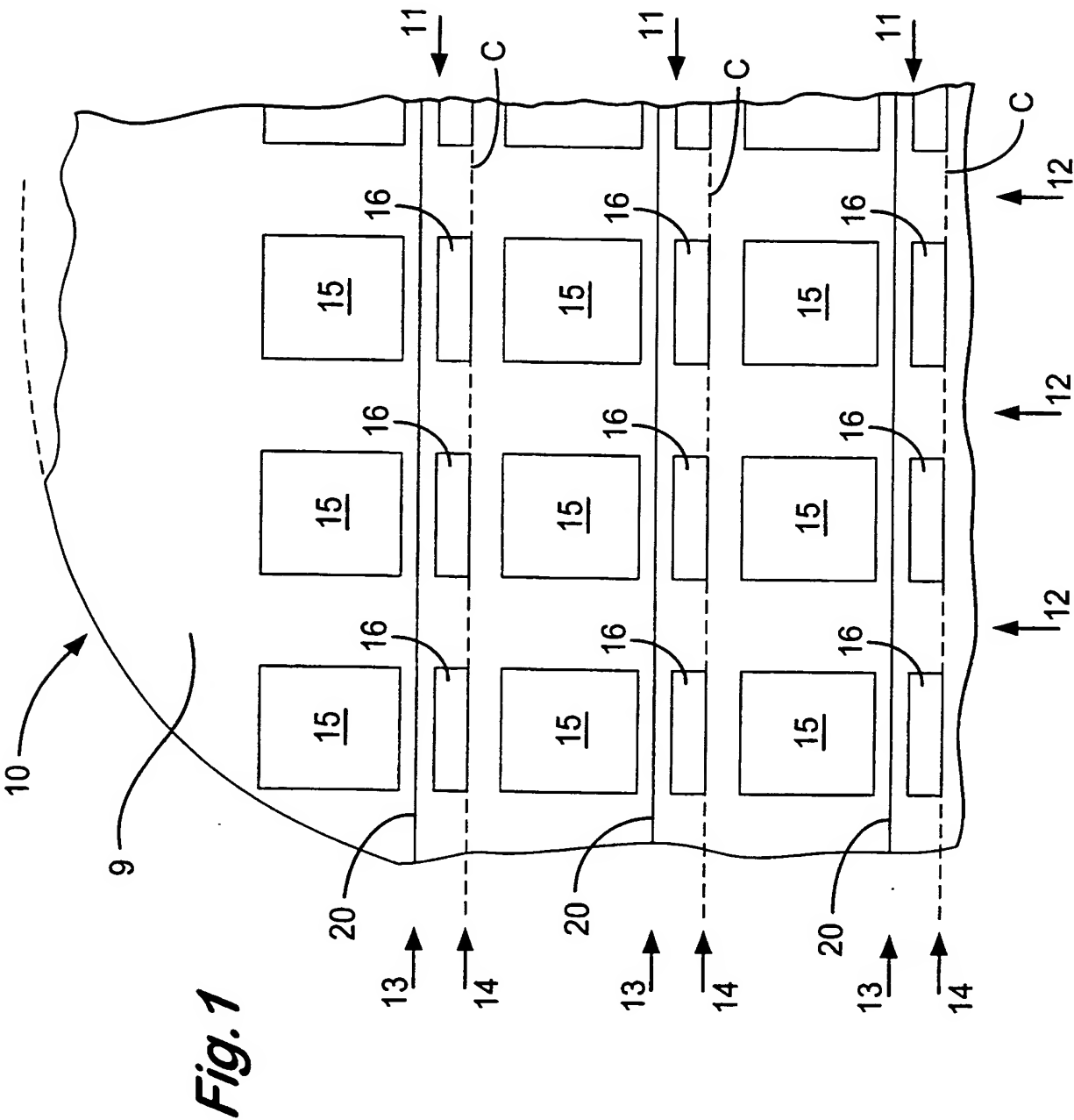
9. A method as claimed in claim 7 or claim 8 wherein a conductive material bridge electrically connects the anode terminal and the exposed un-coated wick material.

- 20 10. A state capacitor comprising a substrate portion and a capacitive body, which body comprises a porous anode body electrically connected to the substrate portion, an electrically insulating layer formed on the anode body surface area, and a conducting layer formed on the  
25 insulating layer, a surface of which capacitive body

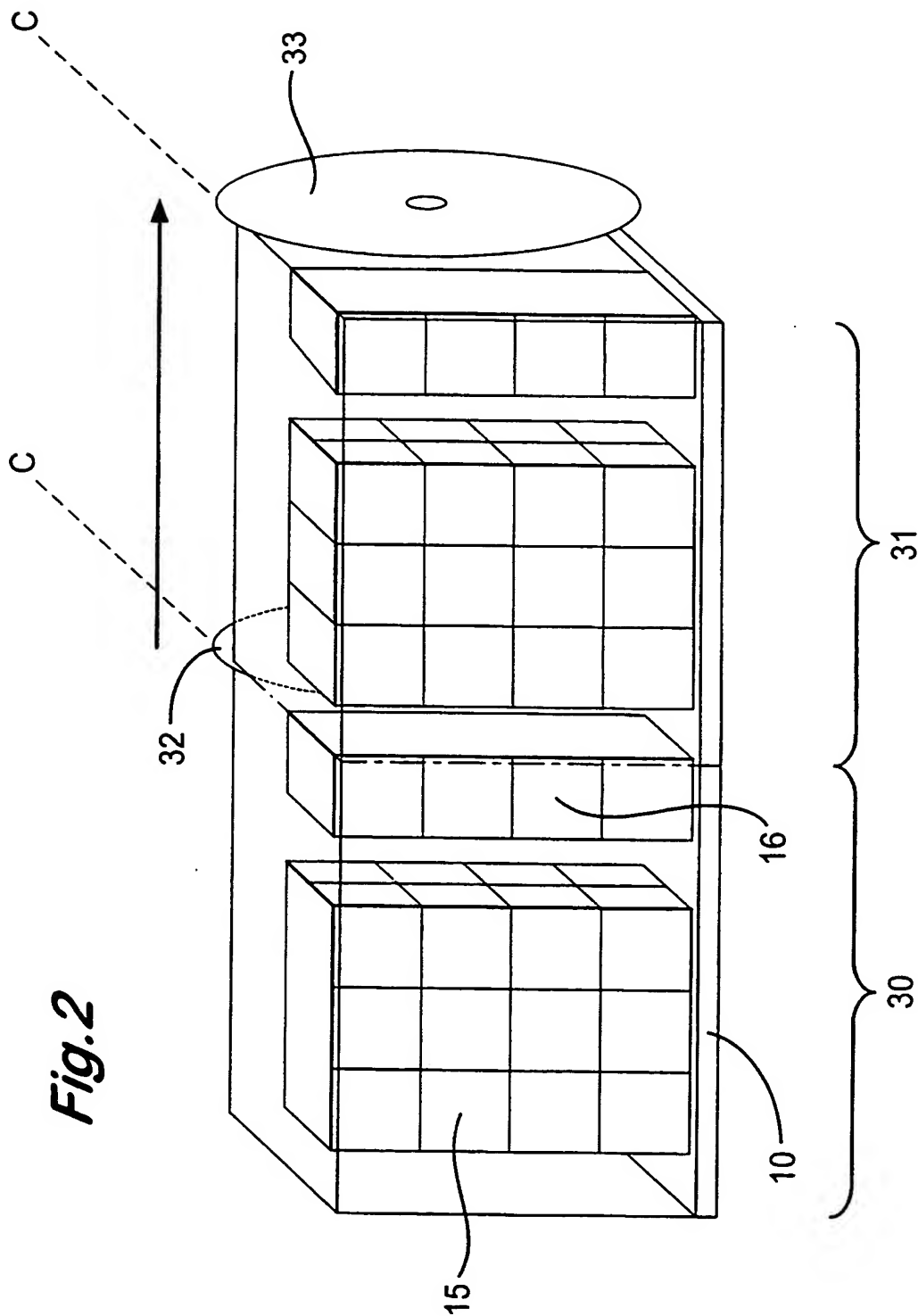
distal to the substrate portion is provided with a cathode terminal, characterised in that an anode terminal is provided adjacent and substantially co-planar with the cathode terminal, an electrically conducting wick providing electrical contact between the substrate portion and the anode terminal, thereby providing a capacitor having anode and cathode terminals on a common face.

11. A capacitor, or method of forming capacitors, as claimed in any preceding claim wherein in each capacitor there are a plurality of anode terminals adjacent and substantially co-planar with the cathode terminal, each anode terminal electrically connected to the substrate by an associated wick.

12. A capacitor, or method of forming a capacitor, as claimed in claim 11 wherein the wicks are each formed from the same porous conducting material as the anode body.

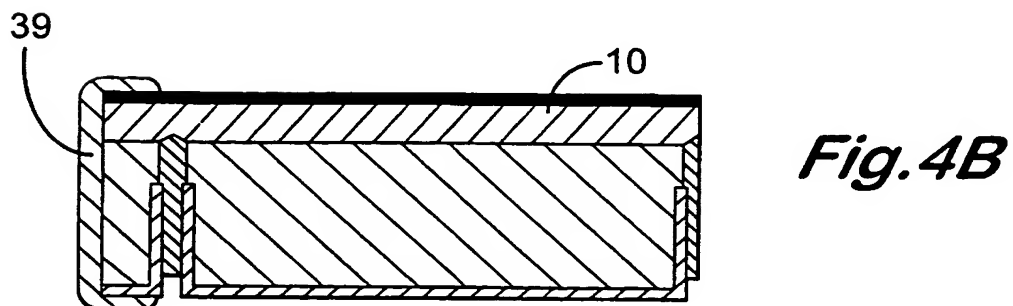
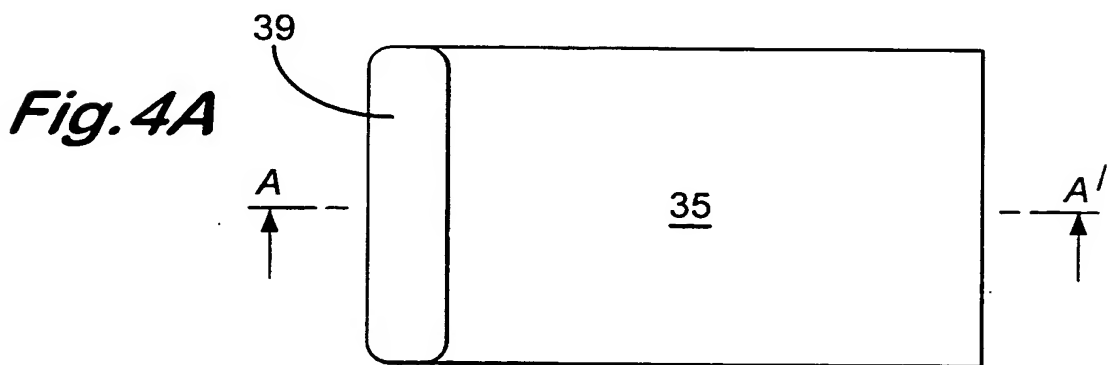
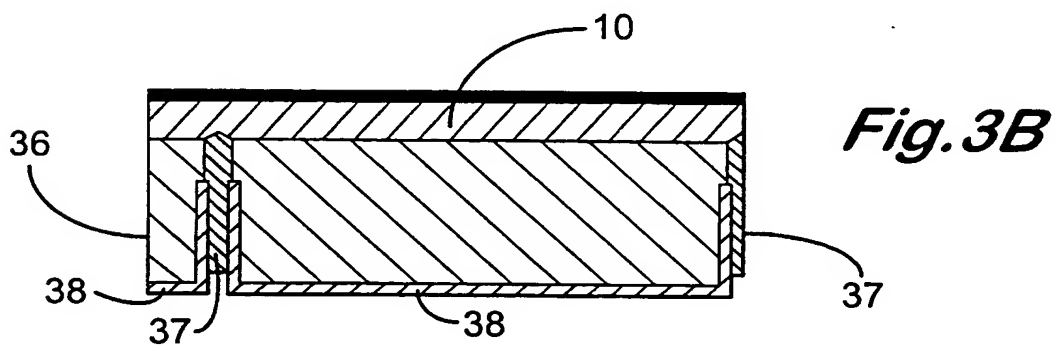
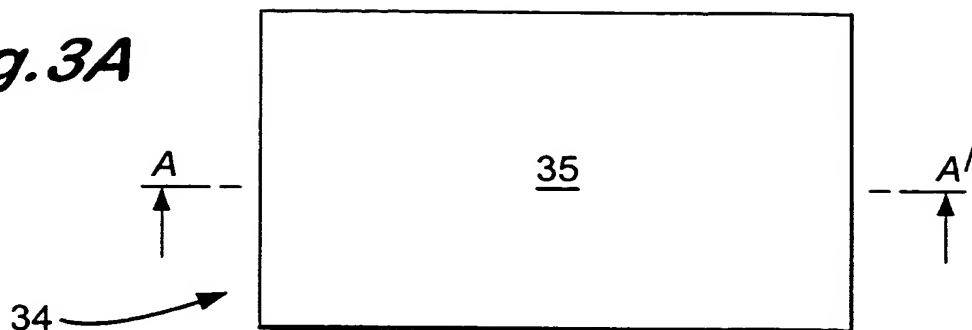


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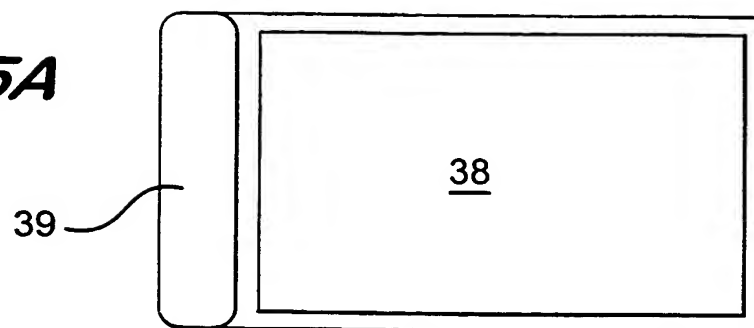
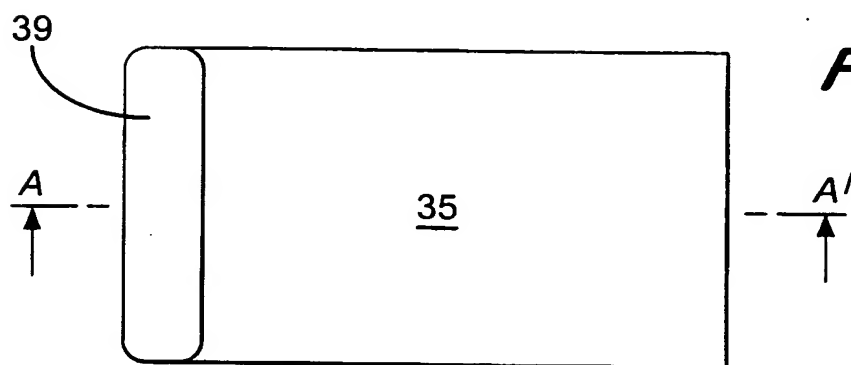
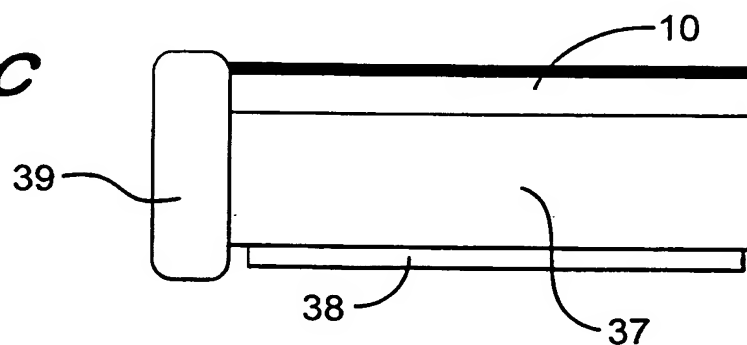
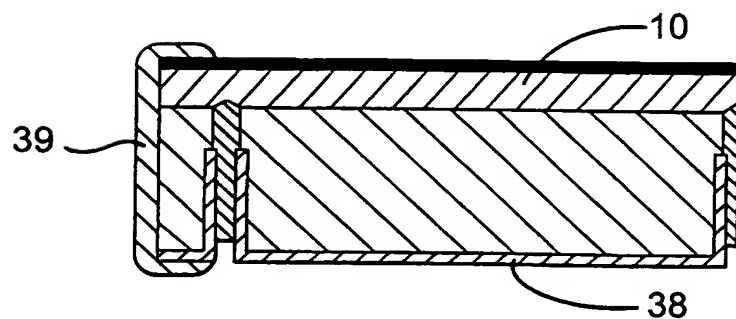


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**Fig.3A**

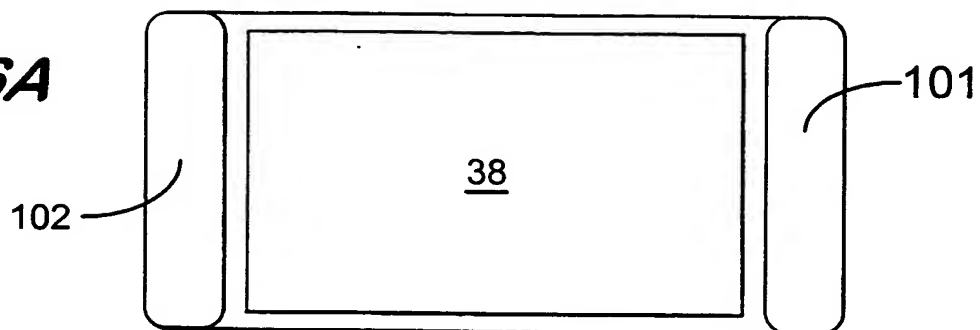


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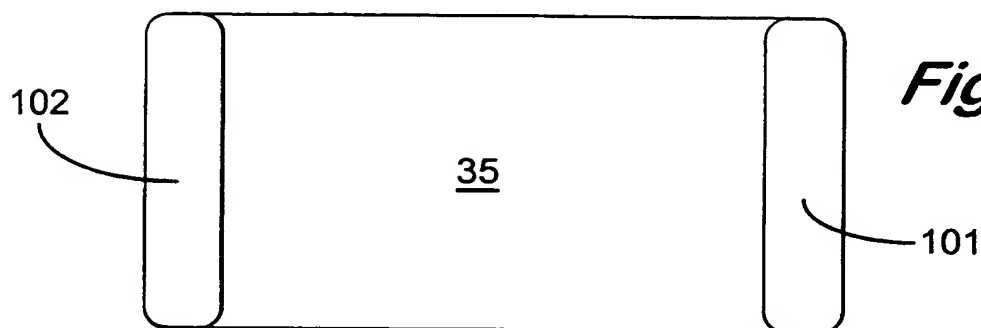
**Fig. 5A****Fig. 5B****Fig. 5C****Fig. 5D**

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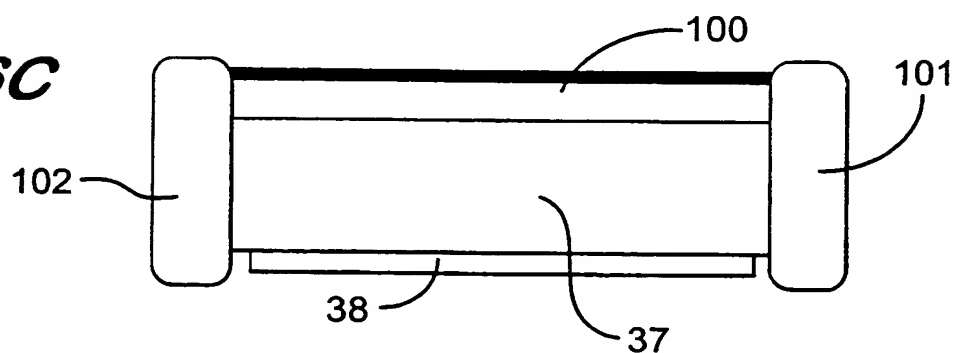
**Fig. 6A**



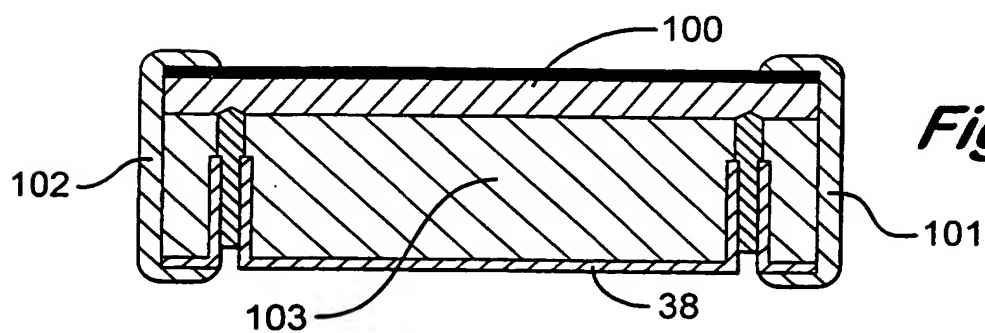
**Fig. 6B**



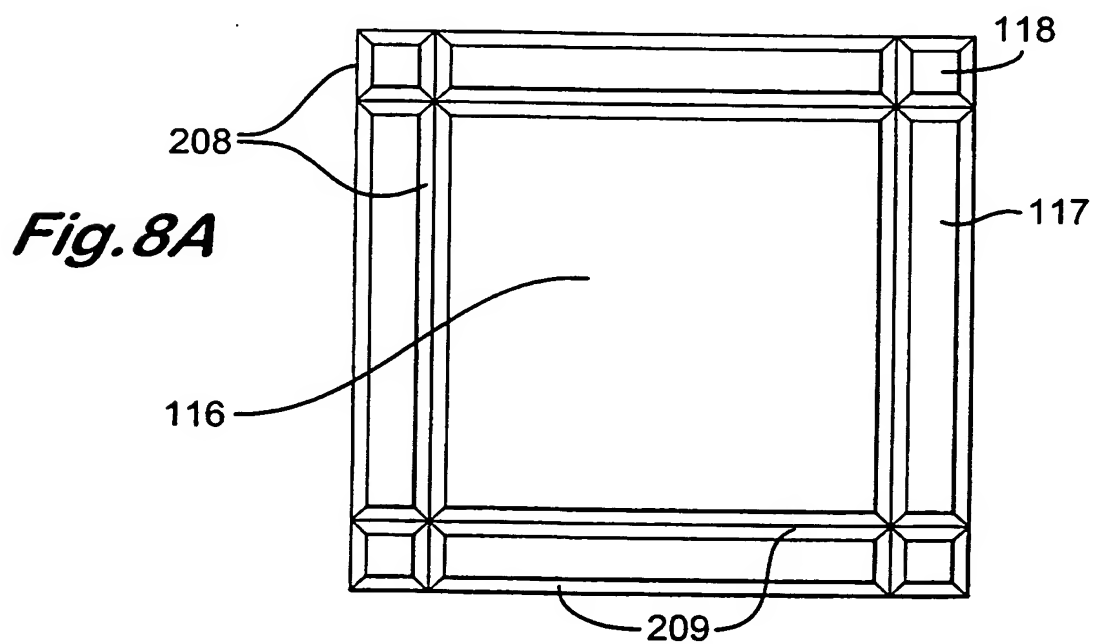
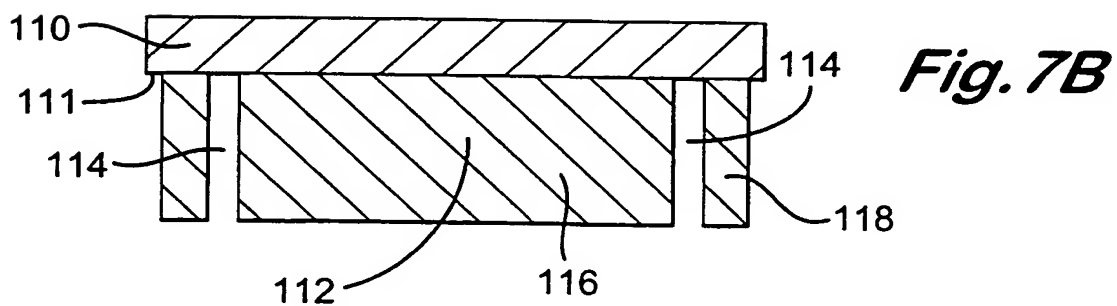
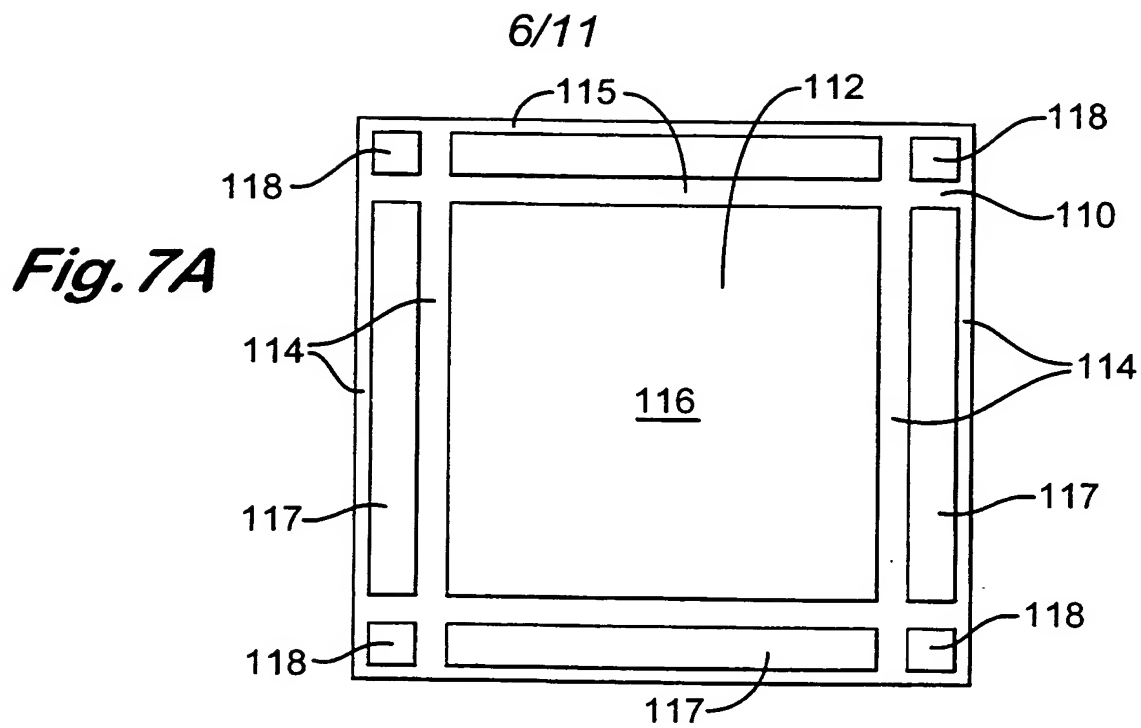
**Fig. 6C**



**Fig. 6D**

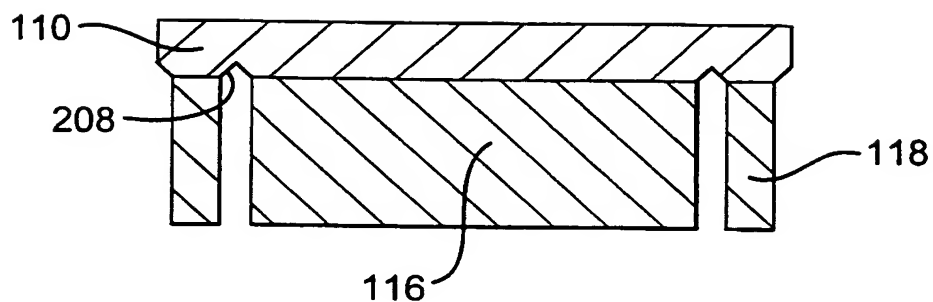




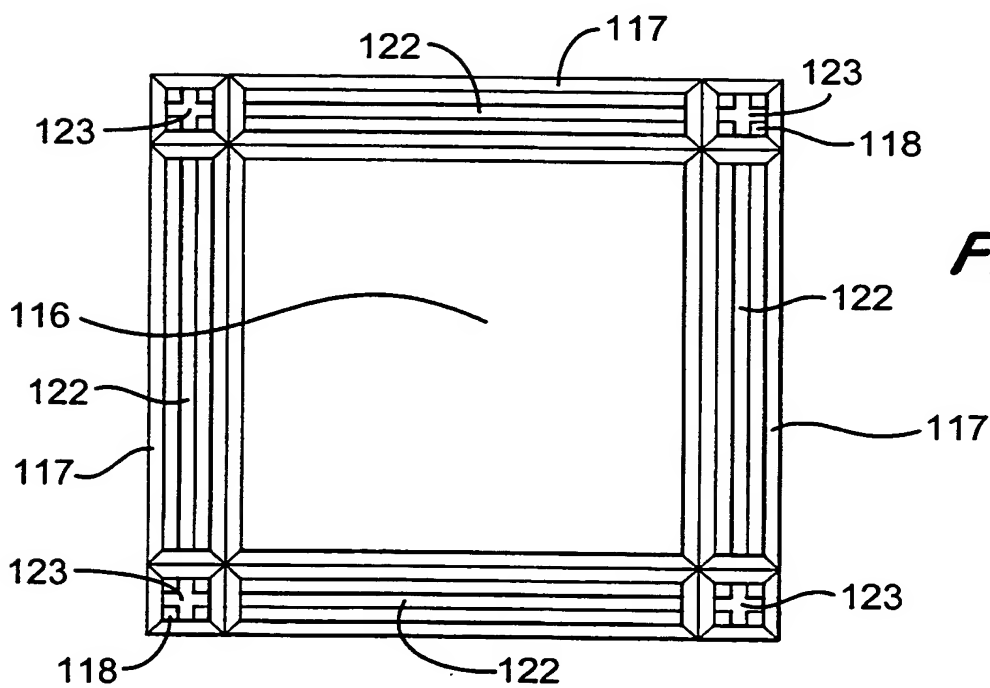


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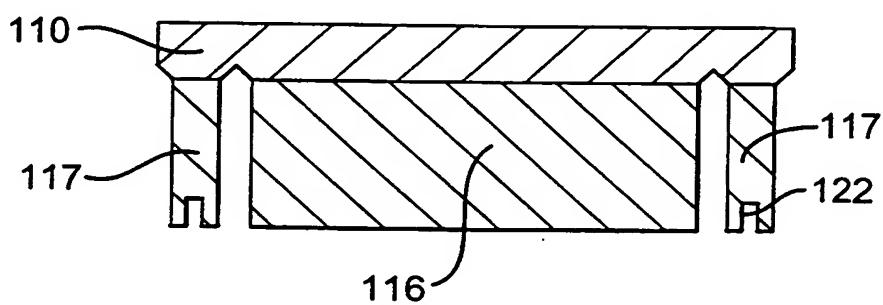
**Fig. 8B**



**Fig. 9A**

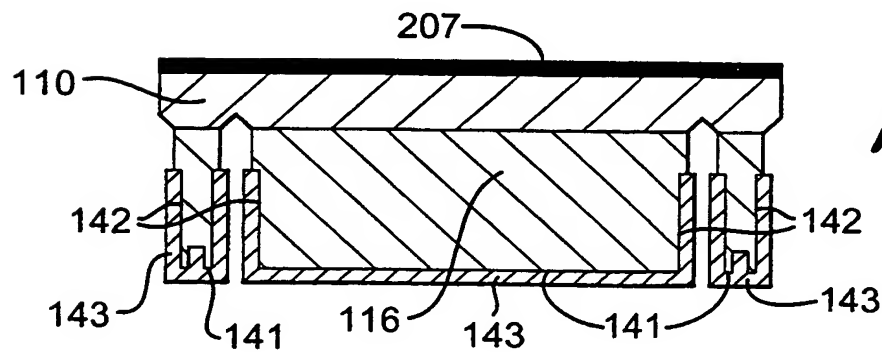
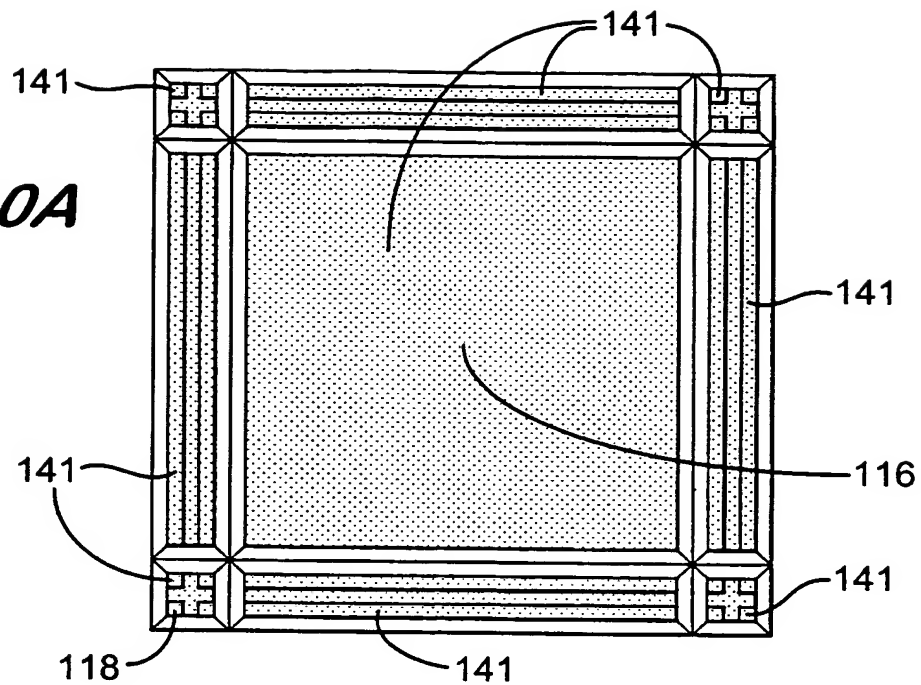


**Fig. 9B**



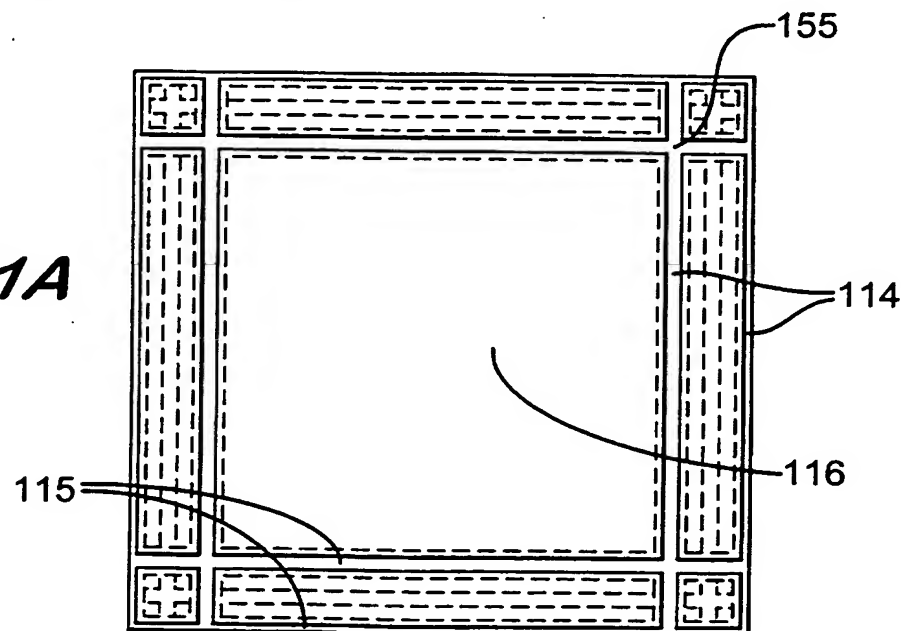
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**Fig. 10A**



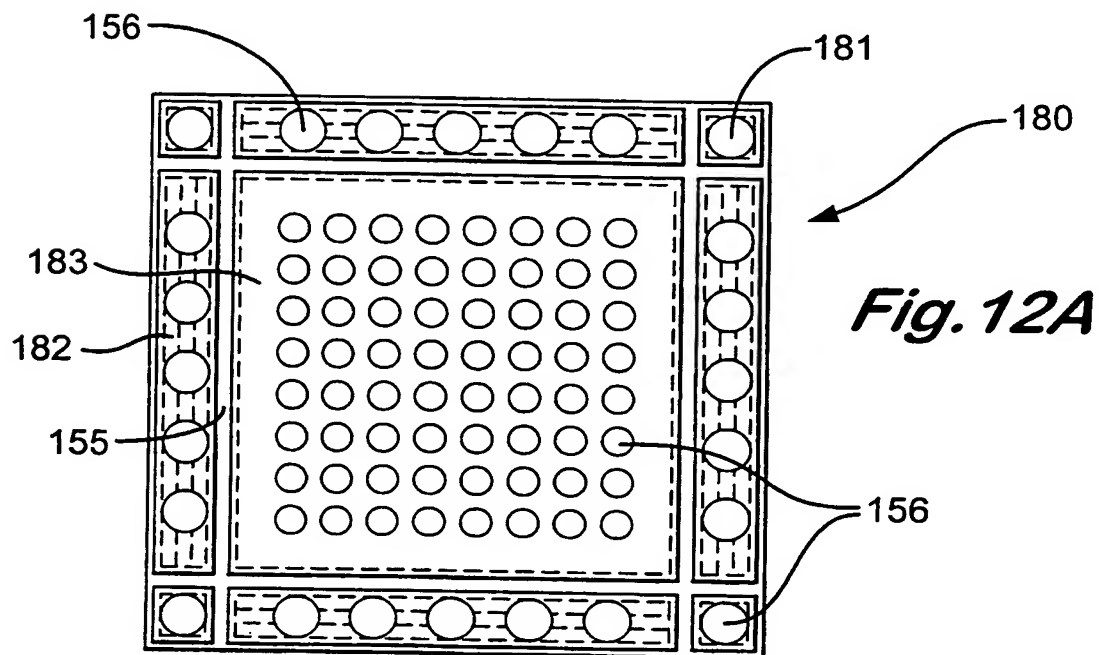
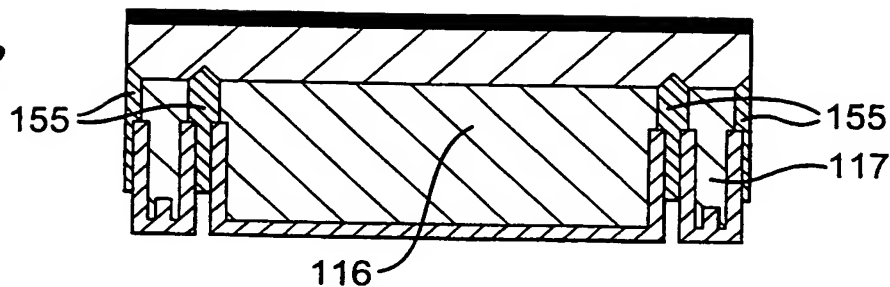
**Fig. 10B**

**Fig. 11A**

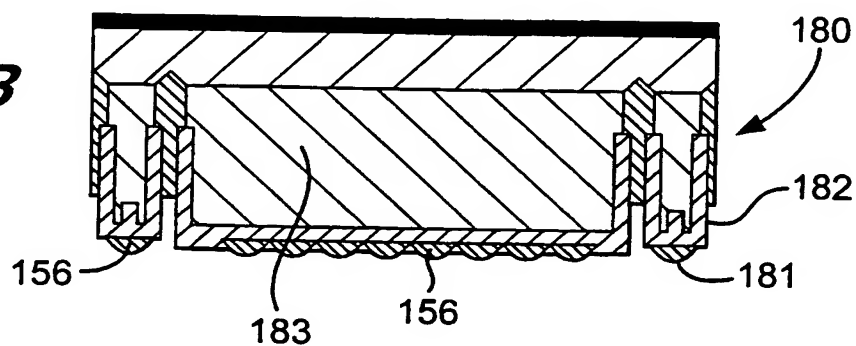


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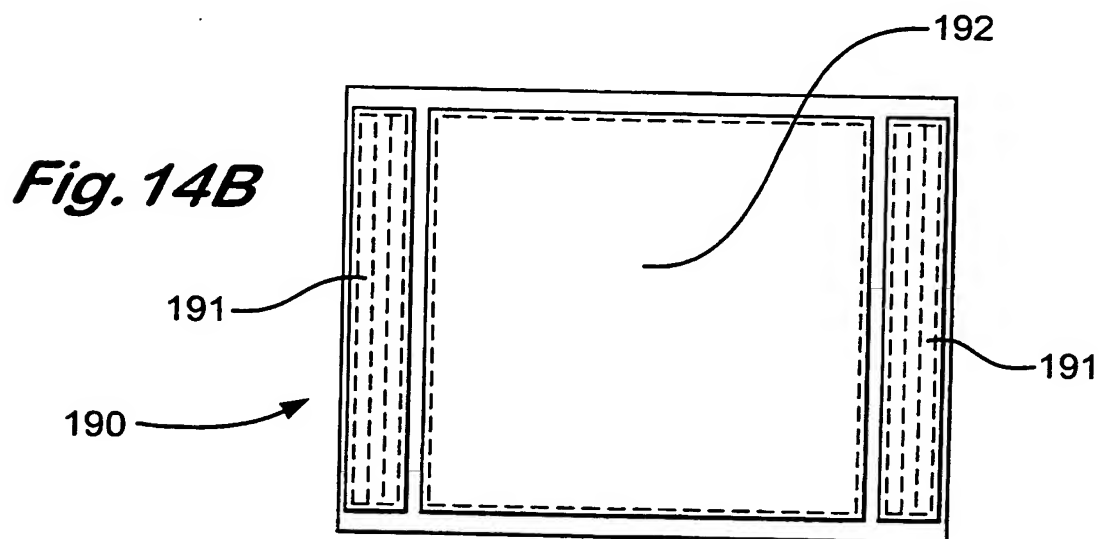
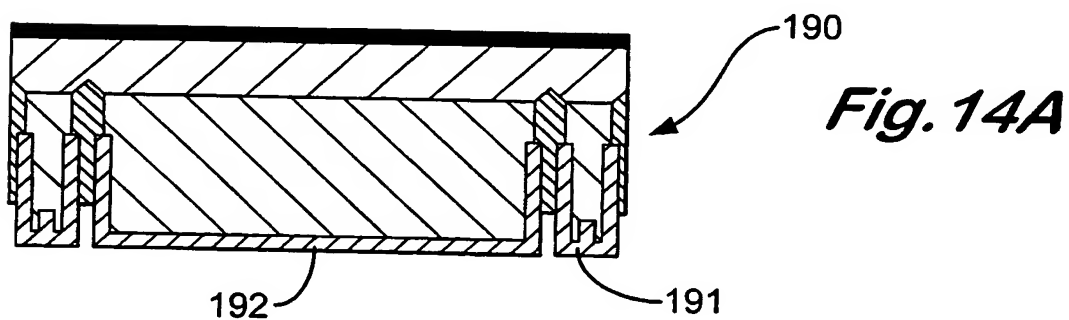
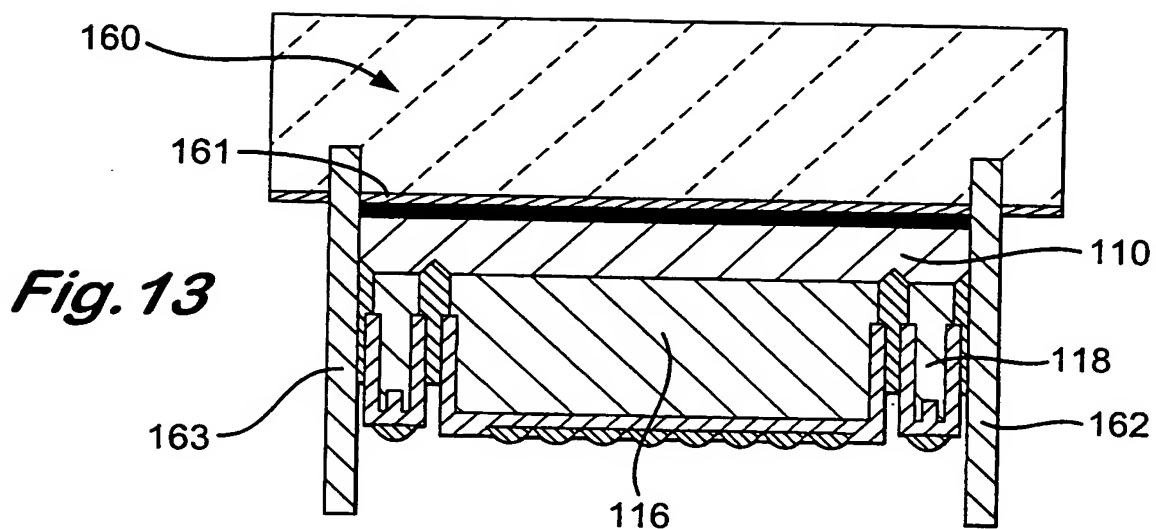
**Fig. 11B**



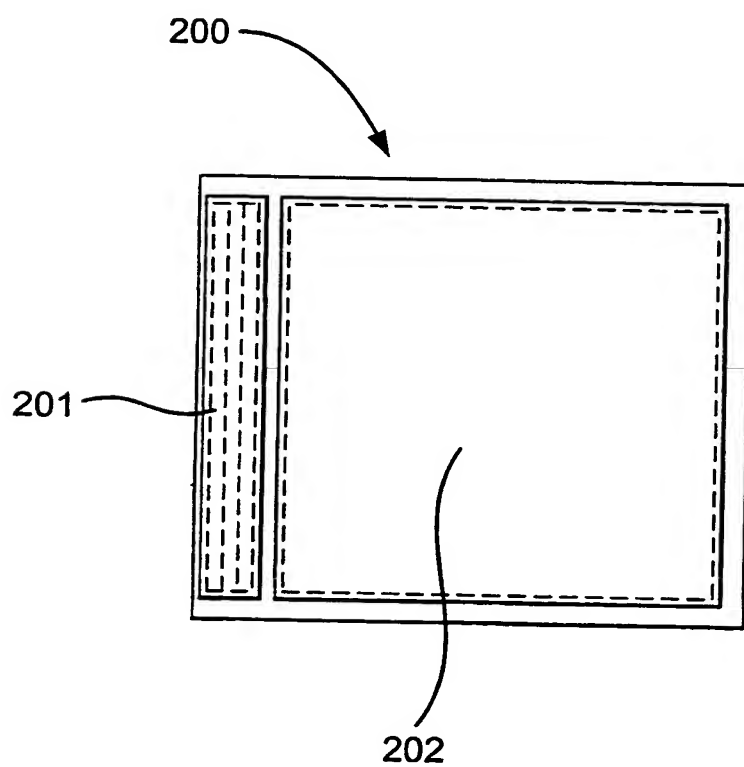
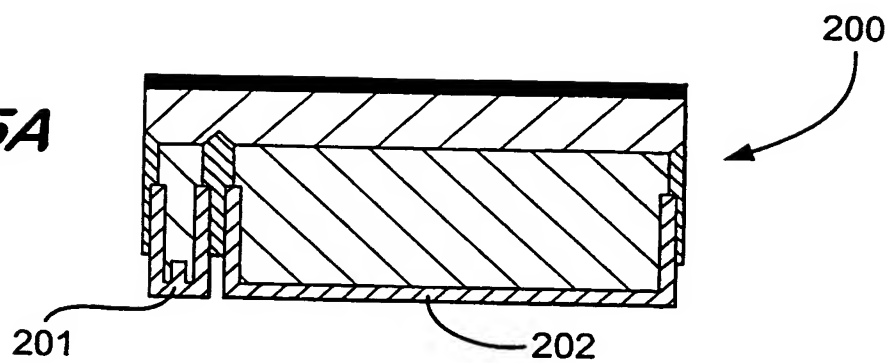
**Fig. 12B**



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*Fig. 15A**Fig. 15B*